

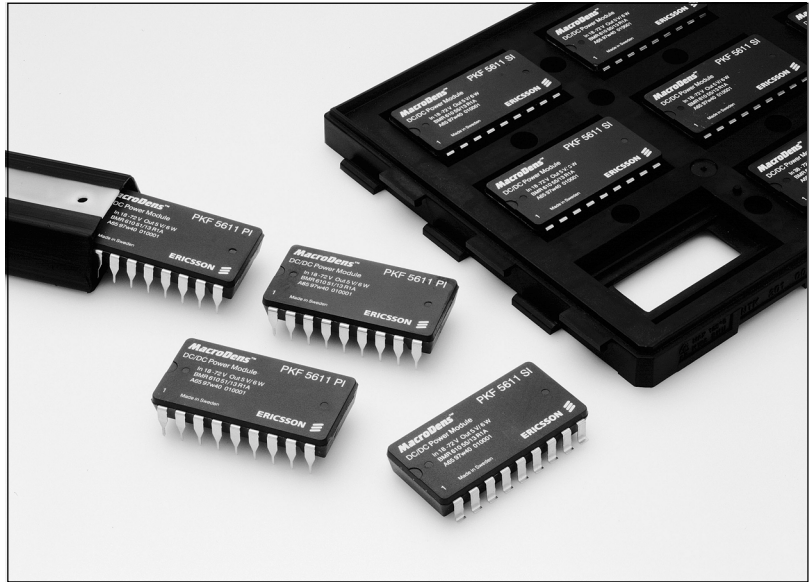
5–6 W DC/DC Power Modules Wide Input Series

- SMD and through-hole versions with ultra low component height 8 mm (0.315 in.)
- 18–72 V input voltage range
- 82% efficiency (typ at 5 V)
- 1,500 Vdc isolation voltage
- Switching frequency synchronization
- MTBF > 4.9 million hours at +55°C case temperature (+40 °C ambient)
- Low EMI measured according to CISPR 22 and FCC part 15J



Patents

US: D357901 DE: M94022763



The MacroDens™ PKF 5000 I series true component level on-board DC/DC power modules are intended as distributed power sources in decentralized 24, 48 and 60 VDC power systems. Utilization of thick film technology and a high degree of silicon integration has made it possible to achieve a MTBF of more than 4.9 million hour.

The highly reliable and rugged over-moulded design and the ultra low height of these DC/DC power modules makes them particularly suited for Information Technology and Telecom (IT&T) and other demanding industrial applications, with board spacing down to 15 mm or 0.6 in. These DC/DC power modules are optimized for free convection cooling and have an operational ambient temperature

range in compliance with present and future application needs, including non temperature controlled environments.

The mechanical design offers the choice of surface mount or through-hole versions, delivered in ready-to-use tubes, trays or tape & reel package, and compatibility with semi and fully aqueous cleaning processes.

The PKF series is manufactured using highly automated manufacturing lines with a world-class quality commitment and a five-year warranty. Ericsson Microelectronics AB has been an ISO 9001 certified supplier since 1991. *For a complete product program please reference the back cover.*

General

Absolute Maximum Ratings

Characteristics		min	max	Unit
T _C	Case temperature at full output power	-45	+100	°C
T _S	Storage temperature	-55	+125	°C
V _I	Continuous input voltage ¹⁾	-0.5	+75	V dc
V _{ISO}	Isolation voltage (input to output test voltage)	1,500		V dc
W _{tr}	Transient input energy		0.01	Ws
V _{RC}	Remote control voltage pin 10, 11	-5	+16	V dc
V _{adj}	Output adjust voltage pin 8, 9	-5	+40	V dc

Stress in excess of Absolute Maximum Ratings may cause permanent damage. Absolute Maximum Ratings, sometimes referred to as no destruction limits, are normally tested with one parameter at a time exceeding the limits of Output data or Electrical Characteristics. If exposed to stress above these limits, function and performance may degrade in an unspecified manner.

Input T_C < T_{Cmax} unless otherwise specified

Characteristics		Conditions	min	typ	max	Unit
V _I	Input voltage range ¹⁾		18		72	V
V _{Ioff}	Turn-off input voltage	(See typical characteristics)	15	16		V
V _{Ion}	Turn-on input voltage	(See typical characteristics)		17.4	17.9	V
C _I	Input capacitance			1.4		μF
P _{Ii}	Input idling power	I _O = 0, T _C = -30...+90 °C	(V _I = 27V) (V _I = 53 V)	244 240		mW
P _{RC}	Input stand-by power	T _C = -30...+90 °C RC connected to pin 17	(V _I = 27V) (V _I = 53 V)	18 67		mW

NOTES:

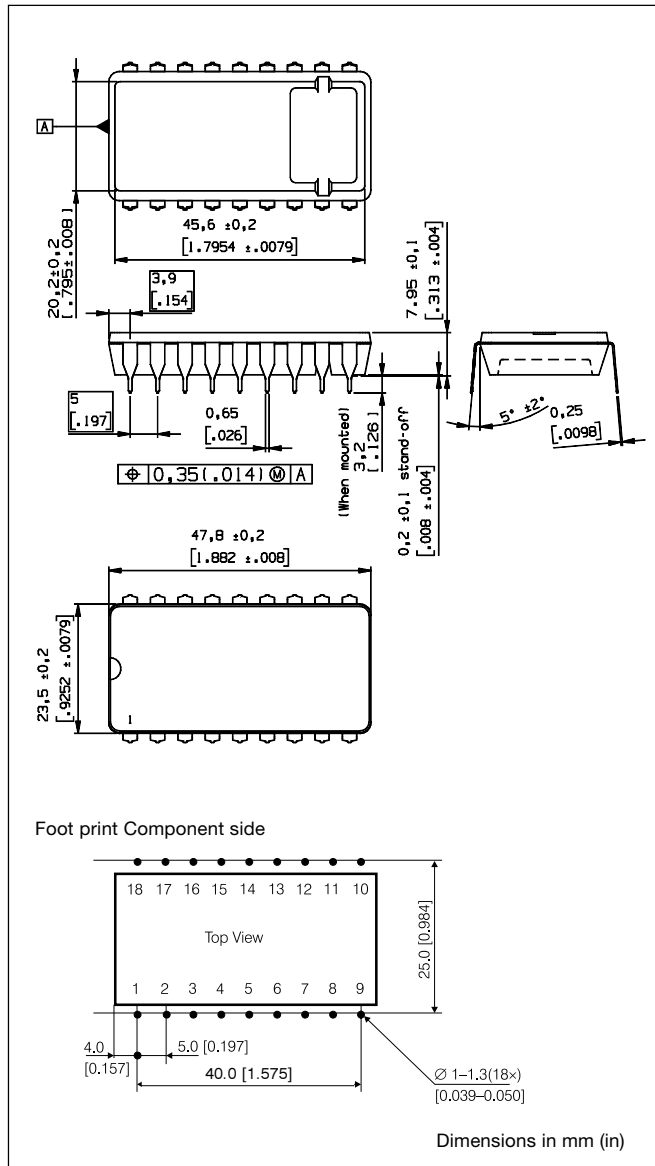
- 1) The input voltage range 18...72 Vdc meets the European Telecom Standard ETS 300 132-2 Nominal input voltage range in 48 V and 60 Vdc power systems, -40.5...-57.0 V and -50.0...-72.0 V respectively. At input voltages exceeding 72 V (abnormal voltage) the power loss will be higher than at normal input voltage and T_C must be limited to max +90 °C. Absolute max continuous input voltage is 75 Vdc. Output characteristics will be marginally affected at input voltages exceeding 72 V.
- 2) The test is applicable for through-hole versions.

Environmental Characteristics

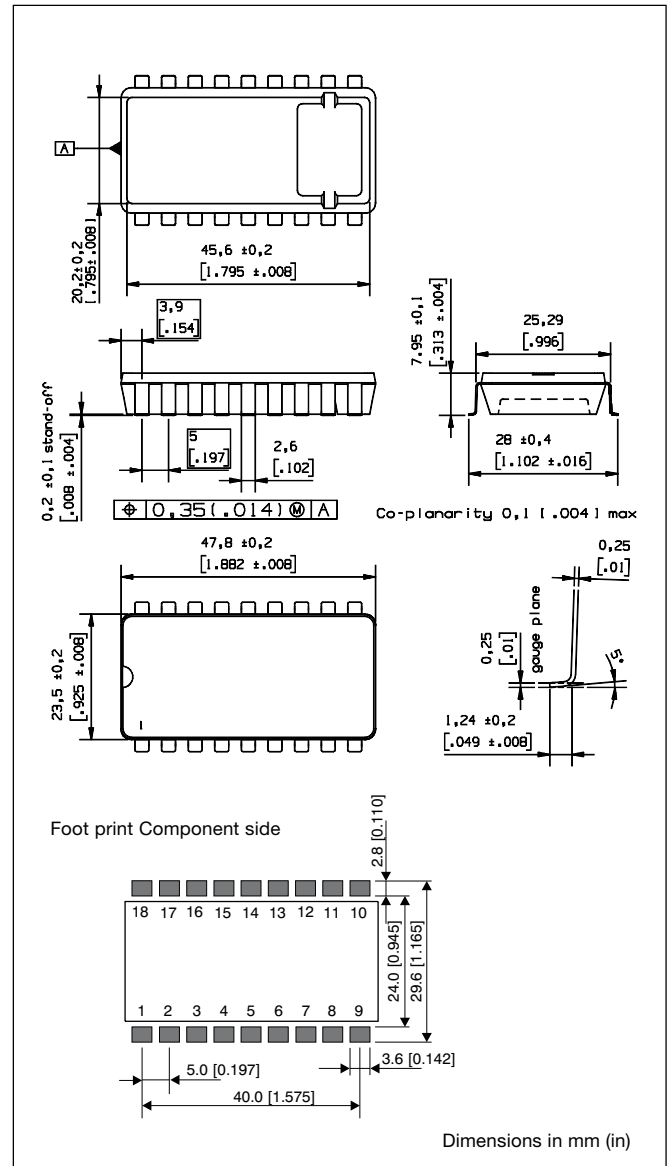
Characteristics	Test procedure & conditions		
Vibration (Sinusoidal)	JESD 22-B103 (IEC 68-2-6 F _d)	Frequency Amplitude Acceleration Number of cycles	10...500 Hz 0.75 mm 10 g 10 in each axis
Random vibration	MIL-STD-883 Method 2026 (IEC 68-2-34 E _d)	Frequency Acceleration density spectrum Duration Reproducibility	10...500 Hz 0.5 g ² /Hz 10 min in 3 directions medium (IEC 62-2-36)
Shock (Half sinus)	JESD 22-B104 (IEC 68-2-27 E _a)	Peak acceleration Shock duration	200 g 3 ms
Temperature change	JESD 22-A104 (IEC 68-2-14 N _a)	Temperature Number of cycles	-40°C...+125°C 500
Accelerated damp heat	JESD 22-A101 (IEC 68-2-3 C _a with bias)	Temperature Humidity Duration	85°C 85% RH 1000 hours
Solder resistability ²⁾	JESD 22-B106 (IEC 68-2-20 T _b 1A)	Temperature, solder Duration	260°C 10...13 s
Aggressive environment	IEC 68-2-11 K _a	Duration Temperature Concentration	96 h 35°C 5 %

Mechanical Data

Through-hole version



Surface-mount version



Connections

Pin	Designation	Function
1	Out 1	Output 1. Positive voltage ref. to Rtn.
2	Rtn	Output return.
3-6	NC	Not connected.
7	Sync	Synchronization input.
8	V _{adj}	Output voltage adjust. To set typical output voltage (V _O) connect pin 8 to pin 9.
9	NOR	Connection of Nominal Output voltage Resistor. (See output voltage adjust p. 12).
10	Aux	Internally connected to pin 11.
11	RC	Remote control and turn-on/off input voltage adjust. Used to turn-on and turn-off output.
12-16	NC	Not connected.
17	-In	Negative input.
18	+In	Positive input.

Weight

Maximum 20 g (0.71 oz).

Case

The case consists of semiconductor grade epoxy with embedded pins.

Coefficient of thermal expansion (CTE) is typ. 15 ppm/°C.

Connection Pins

Base material is copper (Cu), first plating is nickel (Ni) and second (outer) plating is palladium (Pd).

Thermal Data

Over-temperature protection

The PKF 5000 series will automatically shut down when the internal junction temperature of the control IC in the converter reaches typ. 150 °C.

It will automatically re-start when the junction temperature cools below typ. 140 °C.

Two-parameter model

This model provides a more precise description of the thermal characteristics to be used for thermal calculations.

Thermally the power module can be considered as a component and the case temperature can be used to characterize the properties. The thermal data for a power module with the substrate in contact with the case can be described with two thermal resistances. One from the case to ambient air and one from case to PB (Printed Board).

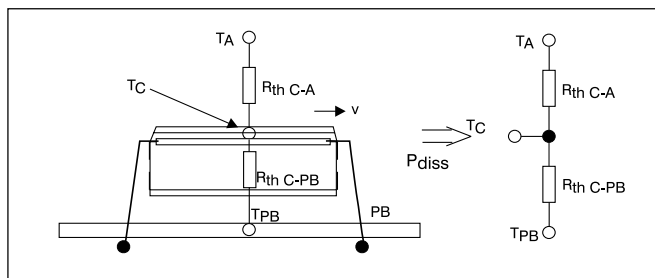
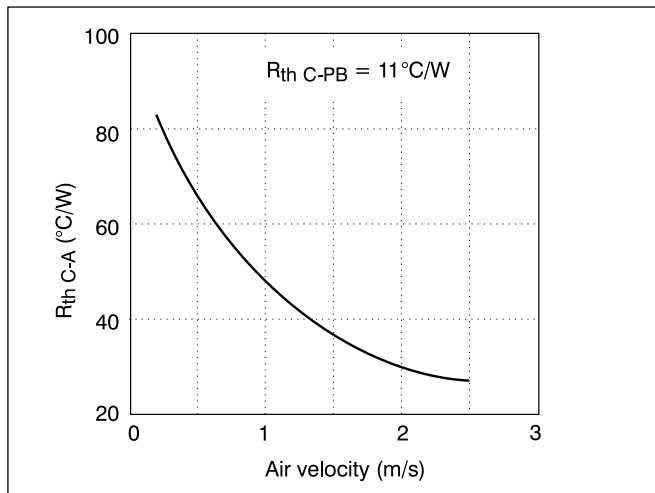
The thermal characteristics can be calculated from the following formula:

$$T_{PB} = (T_C - T_A) \times (R_{th\ C-PB} + R_{th\ C-A}) / R_{th\ C-A} - P_d \times R_{th\ C-PB} + T_A$$

Where:

- P_d : dissipated power, calculated as $P_O \times (1/\eta - 1)$
- T_C : max average case temperature
- T_A : ambient air temperature at the lower side of the power module
- T_{PB} : temperature in the PB between the PKF connection pins
- $R_{th\ C-PB}$: thermal resistance from case to PB under the power module
- $R_{th\ C-A}$: thermal resistance from case to ambient air
- v : velocity of ambient air.
- $R_{th\ C-PB}$ is constant and $R_{th\ C-A}$ is dependent on the air velocity.

Free convection is equal to an air velocity of approx. 0.2 – 0.3 m/s. See figure below.



Reflow Soldering Information

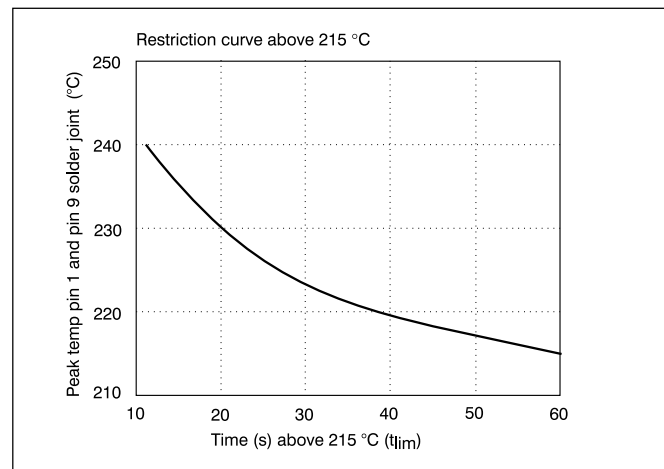
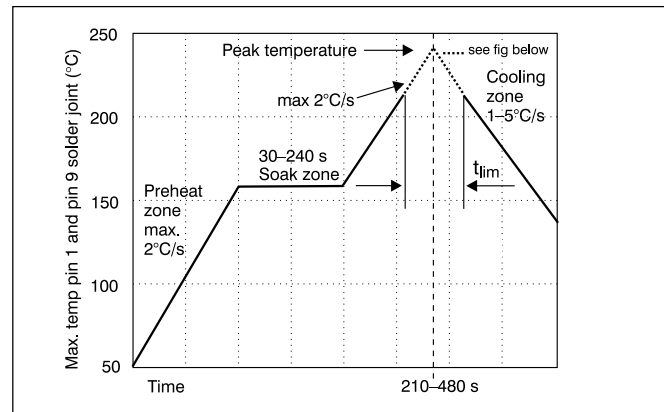
The PKF series of DC/DC power modules are manufactured in surface mount technology. Extra precautions must therefore be taken when reflow soldering the surface mount version. Neglecting the soldering information given below may result in permanent damage or significant degradation of power module performance.

The PKF series can be reflow soldered using IR, Natural Convection, Forced Convection or Combined IR/Convection Technologies. The high thermal mass of the component and its effect on ΔT (°C) requires that particular attention be paid to other temperature sensitive components.

IR Reflow technology may require the overall profile time to be extended to approximately 8–10 minutes to ensure an acceptable ΔT . Higher activity flux may be more suitable to overcome the increase in oxidation and to avoid flux burn-up.

The general profile parameters detailed in the diagram, with this extended time to reach peak temperatures, would then be suitable.

Note! These are maximum parameters. Depending on process variations, an appropriate margin must be added.



Palladium plating is used on the terminal pins. A pin temperature (T_p) in excess of the solder fusing temperature (+183°C for Sn/Pb 63/37) for more than 25 seconds and a peak temperature above 195°C, is required to guarantee a reliable solder joint.

Both pin 1 and pin 9 must be monitored.

No responsibility is assumed if these recommendations are not strictly followed.

Safety

The PKF Series DC/DC power modules are designed in accordance with EN 60 950, *Safety of information technology equipment including electrical business equipment*. SEMKO approval pending.

The DC/DC power module shall be installed in an end-use equipment and considerations should be given to measuring the case temperature to comply with T_{Cmax} when in operation. Abnormal component tests are conducted with the input protected by an external 3 A fuse. The need for repeating these tests in the end-use appliance shall be considered if installed in a circuit having higher rated devices.

When the supply to the DC/DC power module meets all the requirements for SELV (<60 V dc), the output is considered to remain within SELV limits (level 3). The isolation is an operational insulation in accordance with EN 60 950.

The DC/DC power module is intended to be supplied by isolated secondary circuitry and shall be installed in compliance with the requirements of the ultimate application. If they are connected to a 60 V DC system reinforced insulation must be provided in the power supply that isolates the input from the mains. Single fault testing in the power supply must be performed in combination with the DC/DC power module to demonstrate that the output meets the requirement for SELV. One pole of the input and one pole of the output is to be grounded or both are to be kept floating.

The terminal pins are only intended for connection to mating connectors of internal wiring inside the end-use equipment.

These DC/DC power modules may be used in telephone equipment in accordance with paragraph 34 A.1 of UL 1459 (Standard for Telephone Equipment, second edition).

The galvanic isolation is verified in an electric strength test. Test voltage (V_{ISO}) between input and output is 1,500 V dc for 60 s. In production the test duration is decreased to 1 s.

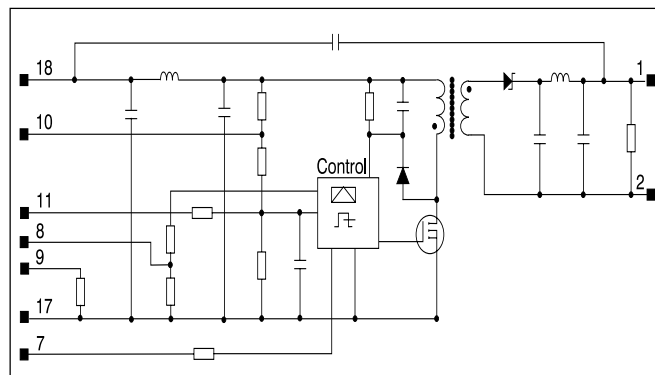
The capacitor between input and output has a value of 1 nF and the leakage current is less than 1 μ A @ 53 V dc.

The case is designed in non-conductive epoxy. Its flammability rating meets UL 94V-0. The oxygen index is 34%.

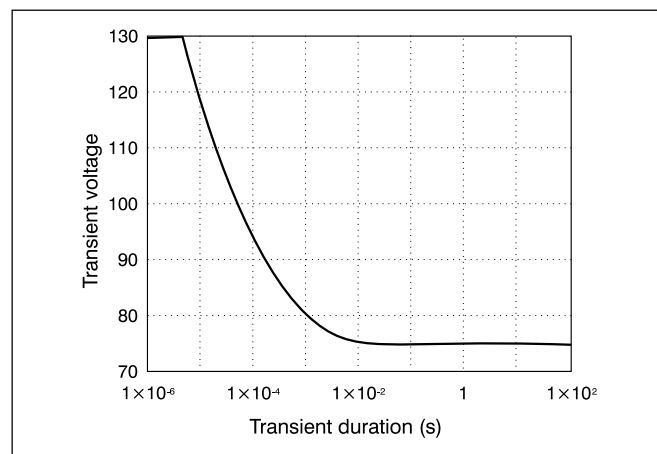
Electrical Data

Fundamental circuit diagrams

Single output



Transient input voltage



Single voltage pulse at +25 °C ambient temperature.

PKF 5510 PI, SI

$T_C = -30 \dots +90^\circ\text{C}$, $V_I = 18 \dots 72\text{V}$ and pin 8 connected to pin 9 unless otherwise specified.

Output

Characteristics		Conditions		Output 1			Unit
				min	typ	max	
V _{Oi}	Output voltage initial setting and accuracy	T _C = +25°C, I _O = 1.5 A, V _I = 53 V		3.27	3.30	3.33	V
	Output adjust range ¹⁾			2.80		3.80	V
V _O	Output voltage tolerance band	Long term drift incl.	I _O = 0.15...1.5 A	3.00		3.46	V
			I _O = 0.15...1.5 A, V _I = 19–72 V	3.13		3.46	
			I _O = 0.2...1.5 A, V _I = 20-72 V	3.17		3.42	
	Idling voltage	I _O = 0 A			3.8	4.3	V
	Line regulation	I _O = 1,5 A	V _I = 18...36 V	30			mV
			V _I = 38...60 V	30			
			V _I = 50...72 V	15			
	Load regulation	I _O = 0.15...1.5 A, V _I = 53 V		50		200	mV
t _{tr}	Load transient recovery time	I _O = 0.15...1.5 A, V _I = 53 V load step = 0.75 A		100			μs
V _{tr}	Load transient voltage			+150	mV		
				-150	mV		
T _{coeff}	Temperature coefficient ²⁾	I _O = 1.5 A, T _C = +40...+90°C		-0.4			mV/°C
t _r	Ramp-up time	I _O = 1.5 A, 0.15...1.5 ×V _O		2			ms
t _s	Start-up time	I _O = 0.15...1.5A, V _I = 53 V From V _I connection to V _O = 0...0.9×V _{Oi}		5			ms
I _O	Output current			0		1.5	A
P _{Omax}	Max output power ²⁾	Calculated value		5	W		
I _{lim}	Current limiting threshold	T _C < T _{Cmax} , V _O = 3.0 V		1.65	2.30	2.50	A
I _{sc}	Short circuit current	V _O = 0.2...0.5 V, T _A = +25 °C		2.7			A
V _{Oac}	Output ripple & noise	I _O = 1.5 A	20 Hz...5 MHz	20		70	mV _{p-p}
			0.6 ...50 MHz			80	dBμV
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wave, 1V _{p-p} , V _I = 53 V (SVR = 20 log (1 V _{p-p} /V _{Op-p}))		45			dB

¹⁾ See also Operating Information.

²⁾ See Typical Characteristics.

Miscellaneous

Characteristics		Conditions		min	typ	max	Unit
η	Efficiency	$I_o = 1.5\text{ A}$	$V_I = 27\text{ V}$	78	80		%
			$V_I = 53\text{ V}$	75	78		
P_d	Power dissipation		$V_I = 27\text{ V}$		1.2	1.4	W
			$V_I = 53\text{ V}$		1.4	1.7	

PKF 5611 PI, SI

$T_C = -30 \dots +90^\circ\text{C}$, $V_I = 18 \dots 72\text{V}$ and pin 8 connected to pin 9 unless otherwise specified.

Output

Characteristics		Conditions		Output 1			Unit
				min	typ	max	
V _{Oi}	Output voltage initial setting and accuracy	T _C = +25°C, I _O = 0.2 A, V _I = 53 V		5.02	5.05	5.08	V
	Output adjust range ¹⁾			4.30		5.80	V
V _O	Output voltage tolerance band	Long term drift included	I _O = 0.15...1.2 A	4.85		5.25	V
	Idling voltage	I _O = 0 A			5.7	6.0	V
	Line regulation	I _O = 1.2 A	V _I = 18...36 V	50			mV
			V _I = 38...60 V	20			
			V _I = 50...72 V	10			
	Load regulation	I _O = 0.3...1.2 A, V _I = 27 V		135			mV
t _{tr}	Load transient recovery time	I _O = 0.12...12 A, V _I = 53 V load step = 0.6 A		330			μs
V _{tr}	Load transient voltage			+120			mV
				-120			mV
T _{coeff}	Temperature coefficient ²⁾	I _O = 1.2 A, T _C = +40...+90 °C		-1.1			mV/°C
t _r	Ramp-up time	I _O = 1.2 A, 0.1...0.9 ×V _O		1	2	5	ms
t _s	Start-up time	I _O = 0.1...1.2 A, V _I = 53 V From V _I connection to V _O = 0...0.9 ×V _{Oi}		4.8		10	ms
I _O	Output current			0		1.2	A
P _{Omax}	Max output power ²⁾	Calculated value		6			W
I _{lim}	Current limiting threshold	T _C <T _{Cmax} , V _O = 4.0 V		1.3	1.8	2.0	A
I _{sc}	Short circuit current	V _O = 0.2...0.5 V, T _A = +25 °C			2.0	3.5	A
V _{Oac}	Output ripple & noise	I _O = 1.2 A	20 Hz...5 MHz		50	150	mV _{p-p}
			0.6 ...50 MHz			80	dBμV
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wave, 1V _{p-p} , V _I = 53 V (SVR = 20 log (1 V _{p-p} /V _{Op-p}))		60			dB

¹⁾ See also Operating Information.

²⁾ See Typical Characteristics.

Miscellaneous

Characteristics		Conditions		min	typ	max	Unit
η	Efficiency	$I_O = 1.2\text{ A}$	$V_I = 27\text{ V}$	79	83		%
			$V_I = 53\text{ V}$	79	81		
P_d	Power dissipation		$V_I = 27\text{ V}$		1.2	1.6	W
			$V_I = 53\text{ V}$		1.4	1.6	

PKF 5617 PI, SI

$T_C = -30 \dots +90^\circ\text{C}$, $V_I = 18 \dots 72\text{V}$ and pin 8 connected to pin 9 unless otherwise specified.

Output

Characteristics		Conditions		Output 1			Unit		
				min	typ	max			
V _{Oi}	Output voltage initial setting and accuracy	T _C = +25°C, I _O = 0.72 A, V _I = 53 V		6.95	7.00	7.05	V		
	Output adjust range ¹⁾			5.95		8.05	V		
V _O	Output voltage tolerance band	Long term drift included	I _O = 0.086...0.86 A	6.65		7.35	V		
	Idling voltage	I _O = 0 A, V _I =53 V			7.5	7.9	V		
	Line regulation	I _O =0.86 A	V _I = 18...36 V	10			mV		
			V _I = 38...60 V	10					
			V _I = 50...72 V	10					
	Load regulation	I _O = 0.08...0.86 A, V _I = 27 V		120			mV		
t _{tr}	Load transient recovery time	I _O = 0.086...0.86 A, V _I = 53 V load step = 0.43 A		350			μs		
V _{tr}	Load transient voltage			+130			mV		
				-130			mV		
T _{coeff}	Temperature coefficient ²⁾	I _O = 0.86 A, T _C = +40... +90°C		-1.2			mV/°C		
t _r	Ramp-up time	I _O = I _{Omax} , 0.1...0.9 ×V _O , V _I = 53 V		1	3	5	ms		
t _s	Start-up time	I _O = 0.086...0.86 A, V _I = 53 V From V _I connection to V _O = 0.9 ×V _{Oi}			5	10	ms		
I _O	Output current			0		0.86	A		
P _{Omax}	Max output power ²⁾	Calculated value		6			W		
I _{lim}	Current limiting threshold	T _C <T _{Cmax} , V _O = 4.0 V		1.0	1.2	1.6	A		
I _{sc}	Short circuit current	V _O = 0.2...0.5 V, T _A = +25 °C			1.8	3.5	A		
V _{Oac}	Output ripple & noise	I _O =0.86 A	20 Hz...5 MHz	50			150	mV _{p-p}	
			0.6 ...50 MHz				80	dBμV	
SVR	Supply voltage rejection (ac)	f = 100 Hz sine wave, 1V _{p-p} , V _I = 53 V (SVR = 20 log (1 V _{p-p} /V _{O<p-p< sub="">))</p-p<>}		60			dB		

¹⁾ See also Operating Information.

²⁾ See Typical Characteristics.

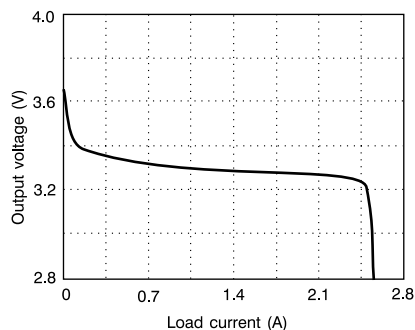
Miscellaneous

Characteristics		Conditions		min	typ	max	Unit
η	Efficiency	$I_O = 0.86\text{ A}$	$V_I = 27\text{ V}$	80	84		%
			$V_I = 53\text{ V}$	80	82		
P_d	Power dissipation		$V_I = 27\text{ V}$		1.1	1.5	W
			$V_I = 53\text{ V}$		1.3	1.5	

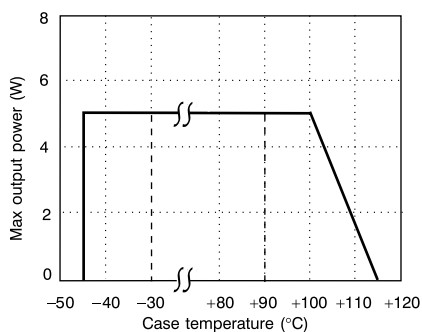
Typical Characteristics

PKF 5510 PI, SI

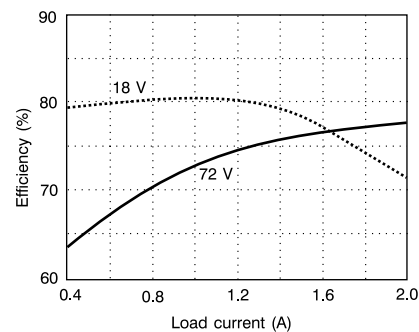
Output characteristic (typ)



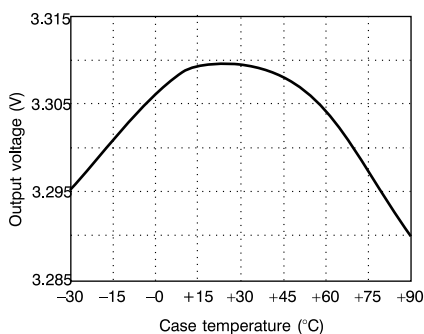
Power derating



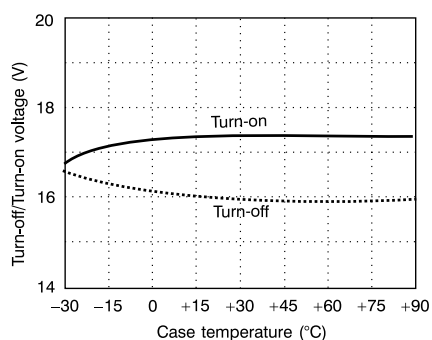
Efficiency (typ) @ $T_A = +25^\circ\text{C}$



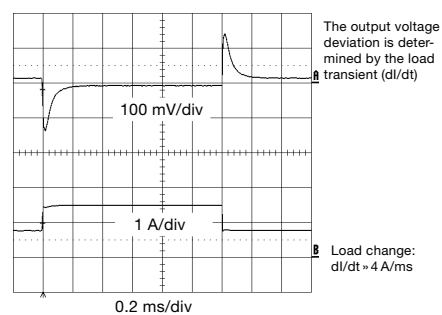
Temperature coefficient



Turn-on/turn-off input voltage

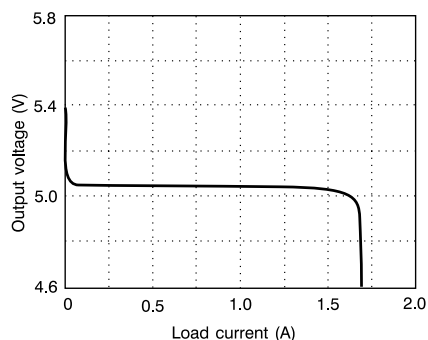


Dynamic load response (typ) @ $+25^\circ\text{C}$

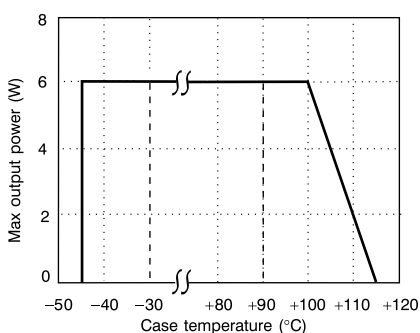


PKF 5611 PI, SI

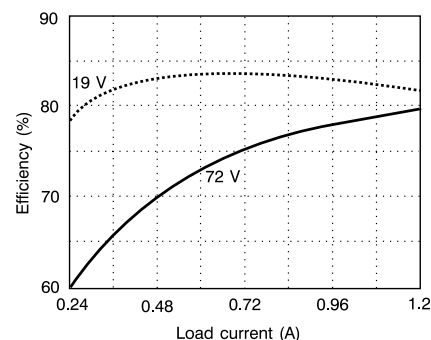
Output characteristic (typ)



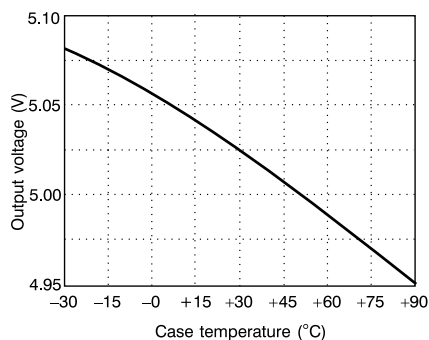
Power derating



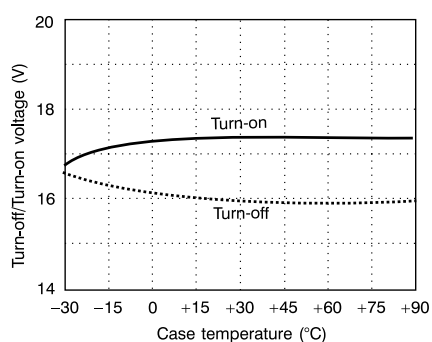
Efficiency (typ) @ $T_A = +25^\circ\text{C}$



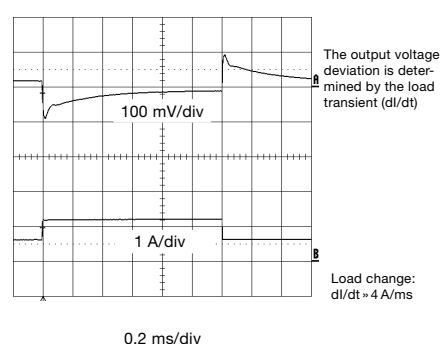
Temperature coefficient



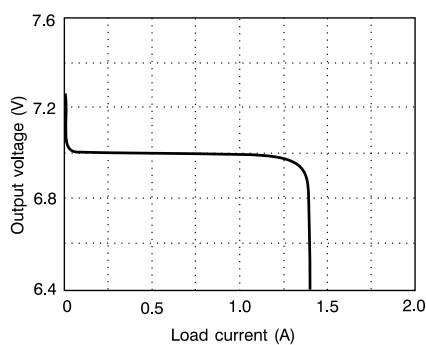
Turn-on/turn-off input voltage



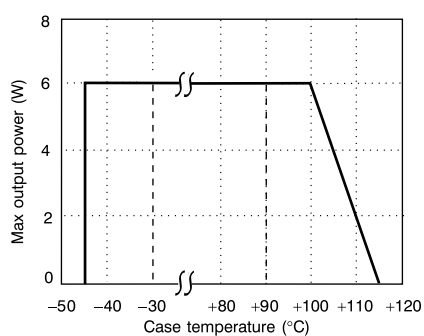
Dynamic load response (typ) @ $+25^\circ\text{C}$



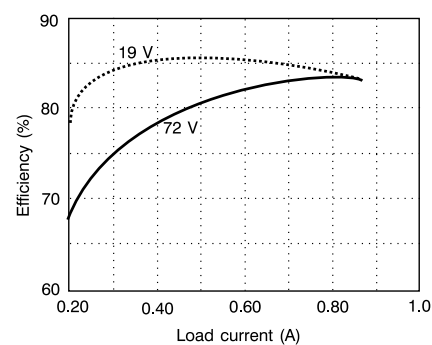
Output characteristic (typ)



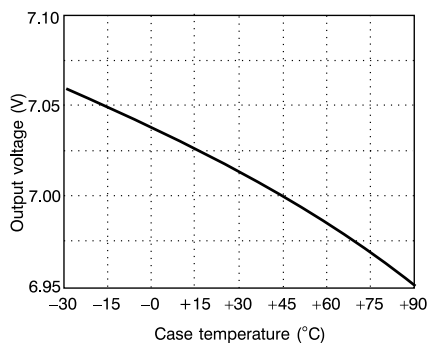
Power derating



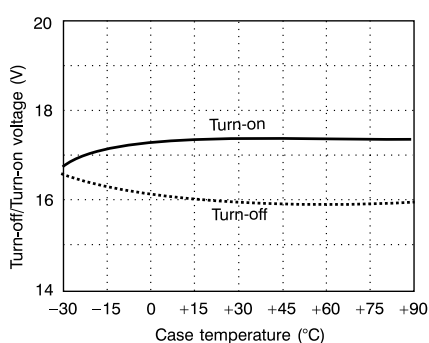
Efficiency (typ) @ $T_A = +25^\circ\text{C}$



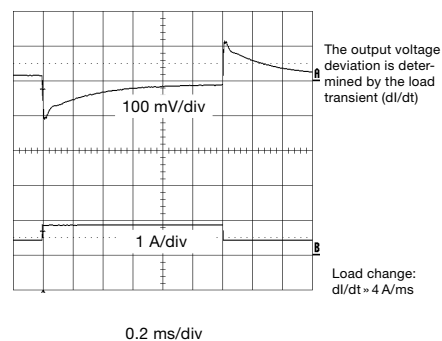
Temperature coefficient



Turn-on/turn-off input voltage



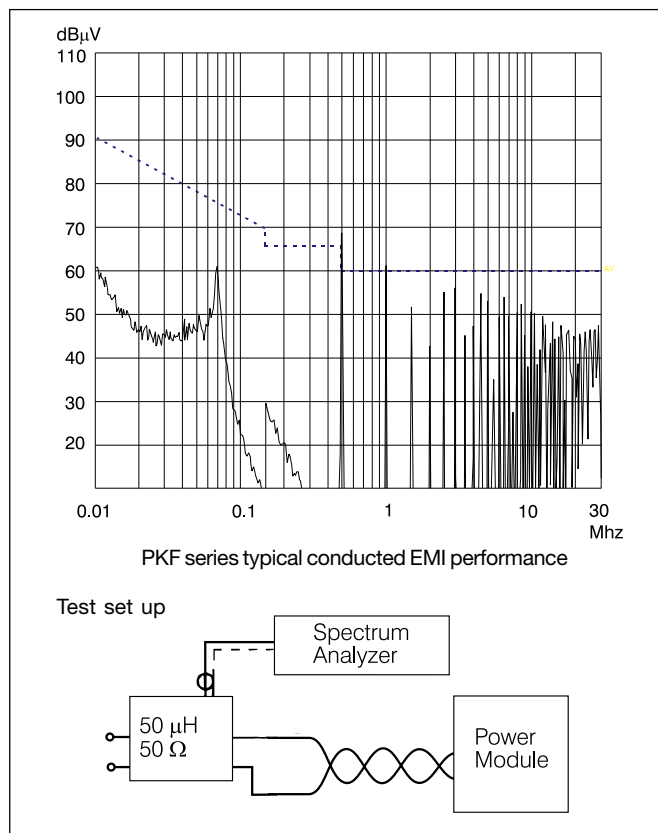
Dynamic load response (typ) @ +25C



EMC Specifications

The fundamental switching frequency is 510 kHz \pm 26 kHz.

Conducted EMI (input terminals)



The PKF meets class A in VDE 0871/0878, FCC Part 15J, and CISPR 22 (EN 55022), except for the fundamental switching frequency.

Conducted EMS

Electro Magnetic Susceptibility is measured by injection of electrical disturbances on the input terminals. No deviation outside the V_O tolerance band will occur under the following conditions:

Frequency range	Voltage level
0.15...300 MHz	1.0 V _{rms}

The signal is amplitude modulated with 1 kHz/80% and applied both differential and common mode.

Radiated EMS (Electro-Magnetic Fields)

Radiated EMS is measured according to test methods in IEC Standard publ. 801-3. No deviation outside the V_O tolerance band will occur under the following conditions:

Frequency range	Voltage level
0.01...200 MHz	3 V _{rms} /m
200...1,000 MHz	3 V _{rms} /m
1...12 GHz	10 V _{rms} /m

ESD

Electro Static Discharge is tested according to IEC publ. 801-2. No destruction will occur if the following voltage levels are applied to any of the terminal pins:

Test	Voltage level
Air discharge	\pm 4 kV
Contact discharge	\pm 2 kV

EFT

Electrical Fast Transients on the input terminals could affect the output voltage regulation causing functional errors on the Printed Board Assembly (PBA). The PKF power modules withstand EFT levels of 0.5 kV keeping V_O within the tolerance band and 2.0 kV without destruction. Tested according to IEC publ. 801-4.

Output Ripple & Noise (V_{Oac})

Output ripple is measured as the peak to peak voltage of the fundamental switching frequency.

Operating Information

Fuse Considerations

To prevent excessive current from flowing through the input supply line, in the case of a short-circuit across the converter input, an external fuse should be installed in the non-earthed input supply line. We recommend using a fuse rated at approximately 2 to 4 times the value calculated in the formula below:

$$I_{inmax} = \frac{P_{Omax}}{(\eta_{min} \times V_{Imin})}$$

For further information, please refer to the fuse manufacturer .

Remote Control (RC)

Turn-on or turn-off can be realized by using the RC-pin. If pin 11 is connected to pin 17 the power module turns off. Normal operation is achieved if pin 11 is open (NC) . To ensure safe turn-off the voltage difference between pin 11 and 17 shall be less than 2.0V. RC is an TTL open collector compatible output with a sink capacity >300 μ A (see fig. 1).

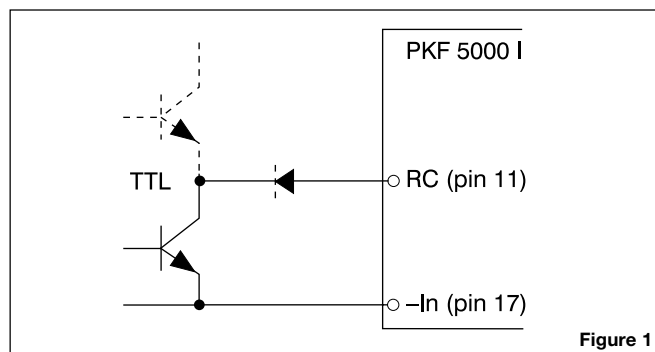


Figure 1

Over Voltage Protection (OVP)

The remote control can also be utilized for OVP by using the external circuitry in figure 2. Resistor values are for 5 V output applications, but can easily be adjusted for other output voltages and the desired OVP level.

Delivery Package Information

Tubes

The PKF-series is delivered in tubes (designated by /A) with a length of 500 mm (19.69 in), see fig. 5.

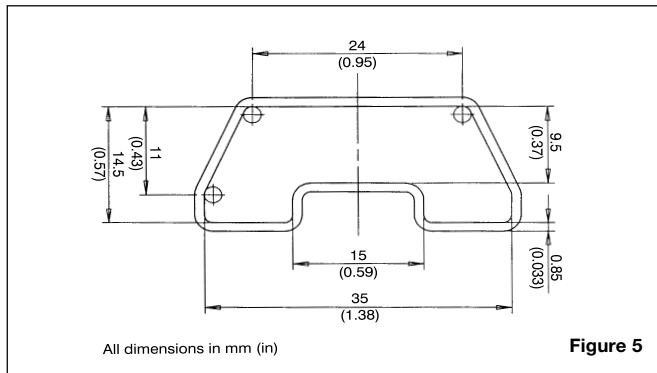


Figure 5

Specification

Material:	Antistatic coated PVC
Max surface resistance:	$10^{11}\Omega/\square$
Color:	Transparent
Capacity:	10 power modules/tube
Weight:	Typ. 60 g
End stops:	Pins

Trays

SMD versions, SI, can be delivered in standard JEDEC trays (designated by /B) on request, see fig. 6. For more information, please contact your local Ericsson sales office.

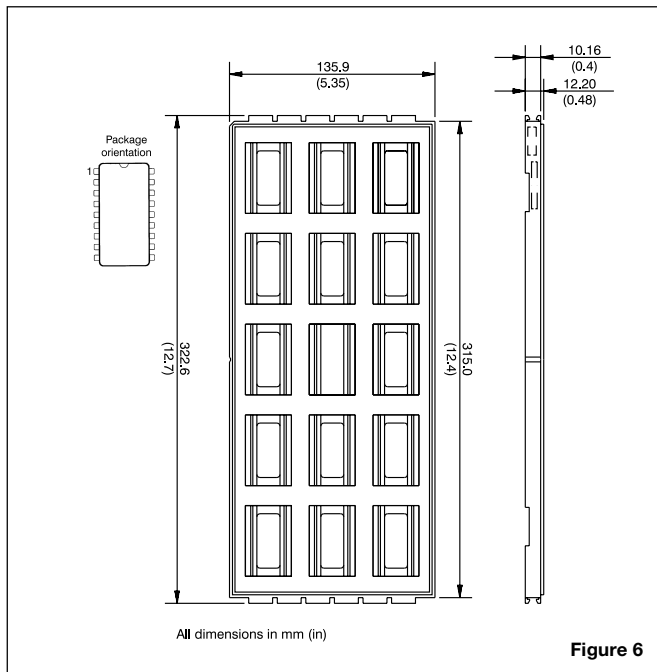


Figure 6

Specification

Material:	Polypropylene (PP)
Max temperature:	125 °C
Max surface resistance:	$10^5\Omega/\square$
Color:	Black

Capacity:	15 power modules/tray
Stacking pitch:	10.16 mm
Weight:	Typ. 130 g
Min. order quantity:	150 pcs (one box contains 10 full trays)

Tape & Reel

SMD versions, SI, can be delivered in standard tape & reel package (designated by /C) on request, see fig. 7. For more information, please contact your local Ericsson sales office.

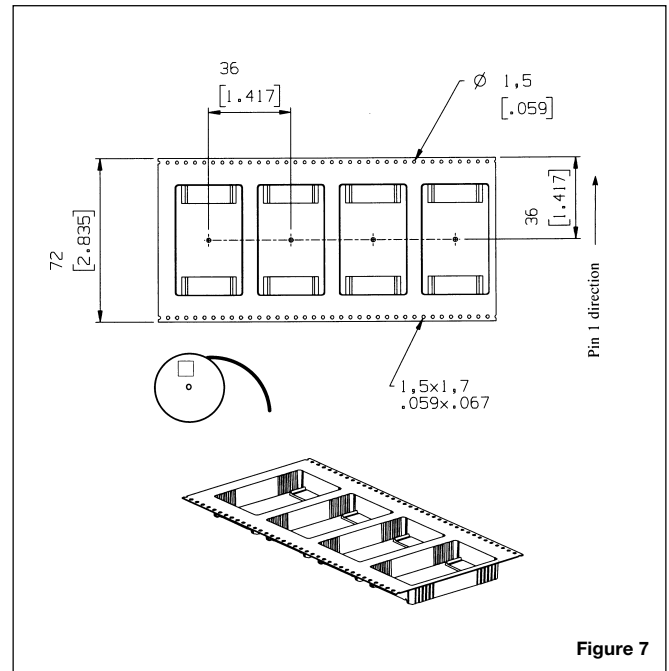


Figure 7

Specification

Tape material:	Conductive polystyrene (PS)
Tape width:	72 mm
Tape pitch:	36 mm
Max surface resistance:	$10^5\Omega/\square$
Tape color:	Black
Cover tape color:	Transparent
Reel diameter:	13"
Reel hub diameter:	7"
Reel capacity:	150 pcs
Full reel weight:	Typ. 3.7 kg
Min. order quantity:	300 pcs (one box contains two reels)

Quality

Reliability

Meantime between failure (MTBF) is calculated to >4.9 million hours at full output power and a pin temperature of +55°C ($T_A = +40^\circ\text{C}$), using the Ericsson failure rate data system. The Ericsson failure rate data system is based on field failure rates and is continuously updated. The data corresponds to actual failure rates of components used in Information Technology and Telecom equipment in temperature controlled environments ($T_A = -5 \dots +65^\circ\text{C}$). The data is considered to have a confidence level of 90%. For more information see Design Note 002.

Quality Statement

The products are designed and manufactured in an industrial environment where quality systems and methods like ISO 9000, 6 σ and SPC, are intensively in use to boost the continuous improvements strategy. Infant mortality or early failures in the products are screened out by a burn-in procedure and an ATE-based final test.

Conservative design rules, design reviews and product qualifications, plus the high competence of an engaged work force, contribute to the high quality of our products.

Warranty

Ericsson Microelectronics warrants to the original purchaser or end user that the products conform to this Data Sheet and are free from material and workmanship defects for a period of five (5) years from the date of manufacture, if the product is used within specified conditions and not opened. In case the product is discontinued, claims will be accepted up to three (3) years from the date of the discontinuation.

For additional details on this limited warranty please refer to Ericsson Microelectronics AB's "General Terms and Conditions of Sales", or individual contract documents.

Limitation of liability

Ericsson Microelectronics does not make any other warranties, expressed or implied including any warranty of merchantability or fitness for a particular purpose (including, but not limited to, use in life support applications, where malfunctions of product can cause injury to a person's health or life).

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Product Program

V_I	V_O/I_O max	P_O max	Ordering No. ^{*)}	
	Output 1		Through-hole	SMD
24/48/60 V (max 75 V dc)	3.3 V/1.5 A 5 V/1.2 A 7 V/0.86 A	5 W 6 W 6 W	PKF 5510 PI PKF 5611 PI PKF 5617 PI	PKF 5510 SI PKF 5611 SI PKF 5617 SI

^{*)} See also Delivery Package Information

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The latest and most complete information can be found on our website!

Data Sheet

EN/LZT 146 32 R1A (Replaces EN/LZT 137 30 R5)
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